Preliminary

SXL-208

800-970 MHz 50 Ohm Power MMIC Amplifier

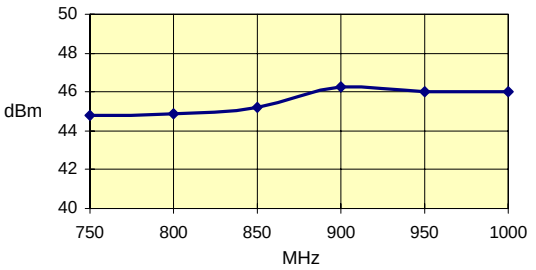
Product Description

Stanford Microdevices' SXL-208 amplifier is a high efficiency GaAs Heterojunction Bipolar Transistor (HBT) MMICs housed in low-cost surface-mountable plastic package. These HBT MMICs are fabricated using molecular beam epitaxial growth technology which produces reliable and consistent performance from wafer to wafer and lot to lot.

These amplifiers are specially designed for use as driver devices for infrastructure equipment in the 800-970 MHz cellular, ISM and narrowband PCS.

Its high linearity make it an ideal choice for multi-carrier as well as digital applications.

Output Third Order Intercept Point vs. Frequency



Product Features

- **Patented High Reliability GaAs HBT Technology**
- **High 3rd Order Intercept : +46dBm Typ. at 900 MHz**
- **High Gain : 18dB Typ. at 900 MHz**
- **Surface-Mountable Power Plastic Package**

Applications

- **Multi-Carrier Systems**
- **Basestation Applications**

Electrical Specifications at Ta = 25C

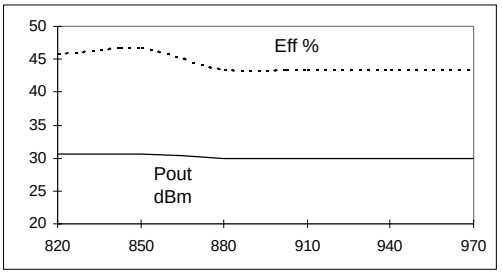
Symbol	Parameters: Test Conditions: Z_0 = 50 Ohms, f = 800-970 MHz		Units	Min.	Typ.	Max.
P_{1dB}	Output Power at 1dB Compression	f = 820-880 MHz f = 800-970 MHz	dBm dBm	30.0	30.5 30.0	
S_{21}	Power Gain	f = 800-970 MHz	dB		18.0	
PAE	Power Added Efficiency	f = 820-880 MHz f = 800-970 MHz	% %		44 40	
VSWR	Input VSWR	f = 820-880 MHz f = 800-970 MHz	-		1.5:1 2.0:1	
VSWR	Output VSWR	f = 820-880 MHz f = 800-970 MHz	-		1.5:1 2.5:1	
IP_3	Third Order Intercept Point	f = 820-880 MHz f = 800-970 MHz	dBm dBm	43	46 45	
I_d	Device Current	Vc=+5V	mA		460	

522 Almanor Ave., Sunnyvale, CA 94086 Phone: (800) SMI-MMIC http://www.stanfordmicro.com

SXL-208 800-970 MHz Power MMIC Amplifier

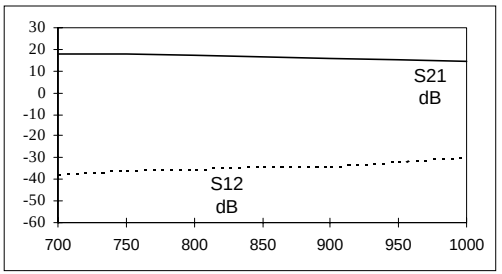
Typical Performance at 25° C (Vc = 5.0V, Ic=460mA)

Output Power and Efficiency vs. Frequency



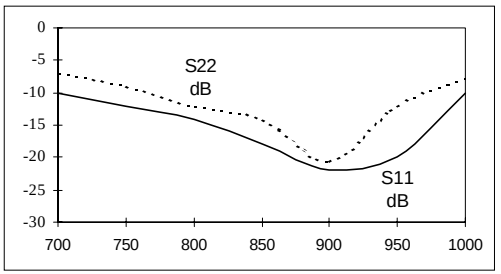
MHz

Gain and Isolation vs. Frequency

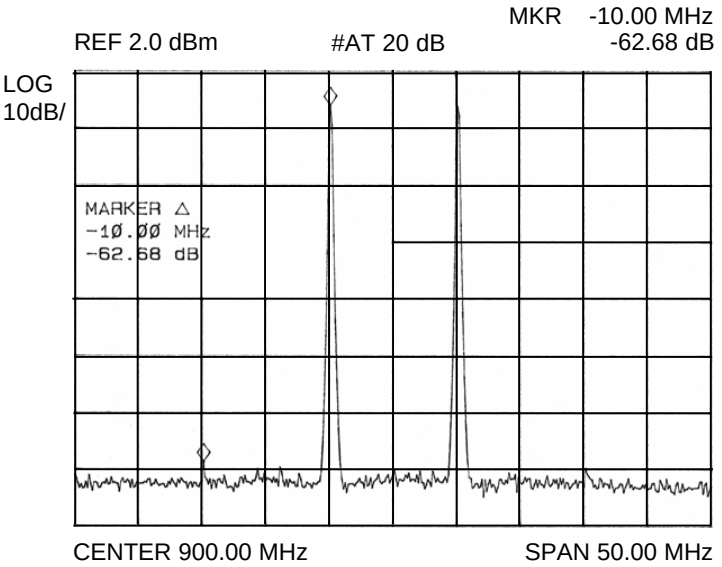


MHz

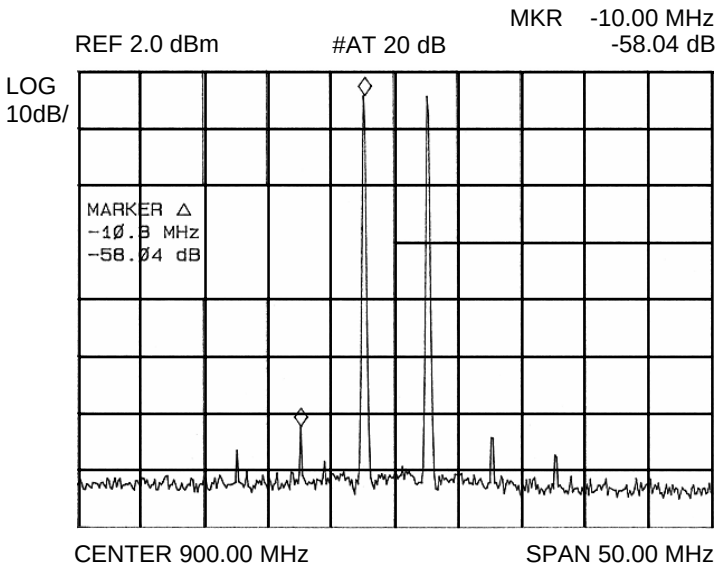
Input & Output Return Loss vs. Frequency



Third Order Intercept Point vs. Output Tone Power



Tone Power= +14dBm, IP3 = +46dBm



Tone Power= +17dBm, IP3 = +46dBm

SXL-208 800-970 MHz Power MMIC Amplifier

Absolute Maximum Ratings

Parameter	Absolute Maximum
Device Voltage	7V
Device Current	700mA
Power Dissipation	5000mW
RF Input Power	100mW
Junction Temperature	+175C
Operating Temperature	-45C to +85C
Storage Temperature	-65C to +175C

Notes:

1. Operation of this device above any one of these parameters may cause permanent damage.

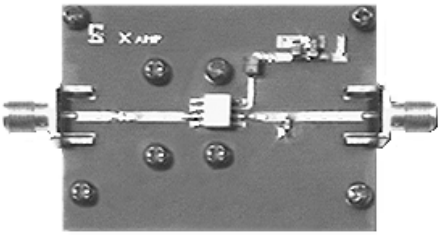
MTTF vs. Temperature @ Id = 460mA

Lead Temperature	Junction Temperature	MTTF (hrs)
+25C	+103C	>10,000,000
+60C	+138C	1,000,000
+85C	+163C	100,000

Thermal Resistance (Lead-Junction): 60° C/W

Part Number Ordering Information

Part Number	Devices Per Reel	Reel Size
SXL-208-TR1	500	7"
SXL-208-TR2	1000	13"
SXL-208-BLK	100/TRAY	-



SXL-208 Evaluation Board (P/N SXL-208EB)

Application Schematic and Bias Circuit for 900 MHz Operation